## **B-7**

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## Linear scaling first-principles calculation method for electronic transport

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#### Abstract:

Recent technology has achieved nano scale fabrication of the electronic devices. The electronic transport properties in such atomic scale materials, where quantum features are remarkable, are much different from that in macro scale materials. Therefore, electronic transport properties in nanoscale devices need to be investigated on the basis of the first-principles calculation, which is a method of numerical calculations of electronic structure based on quantum mechanics. However, since even small electronic devices consist of more than one million atoms, it goes without saying that HPC is necessary to write program codes to investigate their properties. Recently, we proposed a first-principles electronic transport calculation method whose computational cost is linear to the system size. I will explain the details of the electronic transportation calculation for electronic transportation.

# Electronic transport



The electronic transport in nano devices can be evaluated by non-equilibrium Green's function (NEGF) method.

#### • Green's function

$$G(E) = [ES - H(\rho) - \Sigma_L(E) - \Sigma_R(E)]^{-1}$$
  
Hamiltonian for DFT  
(first-principles calculation)

### <u>Charge current</u>

$$\begin{split} I &\equiv \frac{\partial N_{\text{channel}}}{\partial t} \bigg|_{\text{left}} = -\frac{\partial N_{\text{channel}}}{\partial t} \bigg|_{\text{right}} \\ &= \frac{2e}{h} \int T(E) \left( f_L(E) - f_R(E) \right) dE \\ &\approx \frac{2e}{h} \int T(E) \frac{\partial f}{\partial \mu} \left( \frac{\mu_L(E) - \mu_R(E)}{\propto V_{\text{bias}}} \right) dE \\ &\qquad (cf. \text{ Ohm's law: } I = V/R) \end{split}$$

#### • <u>Transmission coefficient</u>

 $T(E) = \operatorname{Tr} \left[ \Gamma_L(E) G(E) \Gamma_R(E) G^{\dagger}(E) \right]$  2

## Divide-conquer method



Finally, all the local Green's functions are put together.

# Algorisms for NEGF and DC-NEGF

### ordinary NEGF

$$\underbrace{\overset{H(\rho)}{\frown} G(E) \to \rho}{\overset{}{\frown}}$$

```
do SCF cycle solve Poisson equation 

do E construct InvG=ES-H-\Sigma_L-\Sigma_R calculate G(E) calculate G(E) calculate \rho^{eq}(E) calculate G^{<}(E) calculate \Delta \rho(E) end do end do
```

### MPI parallelization about E

### DC-NEGF

- The computational cost scales only linearly.
- Massively parallel computing is available.

```
do SCF cycle
   solve Poisson equation
   do E
      construct InvG=ES-H-\Sigma_{I}-\Sigma_{R}
      do site i
         construct InvG<sup>(i)</sup>
         construct InvG^{(i)}-\Sigma^{(i)}
         calculate G^{(i)}(E)
         calculate \rho^{eq(i)}(E)
      end do
      construct G(E) and \rho^{eq}(E)
      calculate G^{<}(E)
                                MPI parallelization
      calculate \Delta \rho(E)
                                about E and clusters
   end do
end do
                                                   4
```

## Transmission of carbon nanotube

program code : OpenMX (<u>http://www.openmx-square.org/</u>)





